

# Contents

<b>1</b>	<b>Introduction</b>	1
	References	3
<b>2</b>	<b>Basic Concepts</b>	5
2.1	Double Heterostructure Ridge Laser Diodes	5
2.2	Heterostructure-Design in Group-III-Nitrides	7
2.2.1	Bandgap and Refractive Index Engineering	7
2.2.2	Piezoelectric Polarization and Active Region Design	10
2.2.3	Band Profile and Charge Carrier Transport	11
2.3	Band Structure and Optical Gain	12
2.4	Laser Dynamics	16
	References	18
<b>3</b>	<b>Thermal Properties</b>	21
3.1	Temperature Dependence of Output Characteristics	21
3.2	Thermal Resistance	23
3.3	Dynamics of Self-Heating	24
	References	28
<b>4</b>	<b>Light Propagation and Amplification in Laser Diodes from Violet to Green</b>	29
4.1	Output Characteristics	29
4.2	Optical Gain	30
4.3	Refractive Index	33
4.4	Antiguinding Factor	34
	References	35
<b>5</b>	<b>Semipolar Crystal Orientations for Green Laser Diodes</b>	37
5.1	Reduction of Internal Electric Field	39
5.2	Birefringence in Semipolar Waveguides	41

5.3	Band Structure of Semipolar Quantum Wells . . . . .	43
5.4	Anisotropic Optical Gain . . . . .	45
5.5	Polarization Switching . . . . .	49
5.6	Comparison of Crystal Planes . . . . .	52
	References . . . . .	53
<b>6</b>	<b>Dynamics of Charge Carriers and Photons . . . . .</b>	<b>55</b>
6.1	Differential Gain and Gain Saturation . . . . .	56
6.2	Charge Carrier Recombination . . . . .	58
6.2.1	Charge Carrier Lifetime at Low Excitation . . . . .	59
6.2.2	Determination of the Recombination Rate . . . . .	59
6.2.3	Charge Carrier Lifetime at Threshold . . . . .	61
6.2.4	Recombination Coefficients . . . . .	62
6.2.5	Limitations of the ABC-Model . . . . .	64
6.3	Gain as Function of Charge Carrier Density . . . . .	64
	References . . . . .	65
<b>7</b>	<b>Short-Pulse Laser Diodes . . . . .</b>	<b>67</b>
7.1	GaN-Based Multi-Section Laser Diodes . . . . .	68
7.2	Tuneability of the Absorber . . . . .	69
7.2.1	Absorption Spectrum . . . . .	69
7.2.2	Charge Carrier Lifetime . . . . .	74
7.3	Absorber and Gain Section Dynamics . . . . .	76
7.4	Bias-Dependence of the Output Characteristics . . . . .	78
7.5	Self-Pulsation and Single-Pulse Generation . . . . .	80
	References . . . . .	83
<b>8</b>	<b>Summary and Conclusions . . . . .</b>	<b>85</b>
	<b>Appendix: Numerical Methods . . . . .</b>	<b>89</b>
	<b>Curriculum Vitae . . . . .</b>	<b>93</b>

GaN-Based Laser Diodes

Towards Longer Wavelengths and Short Pulses

Scheibenzuber, W.G.

2012, XIV, 98 p., Hardcover

ISBN: 978-3-642-24537-4